

Docket No.: 50389-052

PATENT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of	:	Customer Number: 20277
Chihiro KAWAI, et al.	:	Confirmation Number:
Serial No.:	:	Group Art Unit:
Filed: July 08, 2004	:	Examiner:
For: POROUS SEMICONDUCTOR AND METHOD FOR MANUFACTURING SAME	:	

**INFORMATION DISCLOSURE STATEMENT**

Honorable Commissioner for Patents and Trademarks  
Washington, D. C. 20231

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached form PTO-1449. It is respectfully requested that the references be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed with the application and no certification or fee is required.

A copy of the foreign search report is attached for the Examiner's information. Please note this is a PCT application in the entry of the National Phase in the U.S. However, to ensure that these references are available to the Examiner, we are providing copies of these references herewith. Since the Search Report was from the U.S., JPO or EPO search authorities, copies of these references should have been supplied to the USPTO

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under the trilateral agreement and are believed to be in the file of the above-identified application and readily available to the Examiner. Therefore it is believed that Applicants have met all requirements regarding duty of disclosure under 37 CFR 1.56.

Acknowledgement and consideration of these documents are respectfully requested.

Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

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**Date: July 8, 2004**

DT15 DocId:30000000 08 JUL 2004

SHEET 1 OF 1

# INFORMATION DISCLOSURE CITATION IN AN APPLICATION

(PTO-1449)

ATTY. DOCKET NO.  
**50389-052**

SERIAL NO.

**10/500975**APPLICANT  
**Chihiro KAWAI, et al.**FILING DATE  
**July 08, 2004**

GROUP

## U.S. PATENT DOCUMENTS

EXAMINER'S INITIALS	CITE NO.	Document Number Number-Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		US			
		US			
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## FOREIGN PATENT DOCUMENTS

EXAMINER'S INITIALS	CITE NO.	Foreign Patent Document Country Codes -Number 4 -Kind Codes (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Figures Appear	Translation	
						Yes	No
		JP 2001-259434 A (w/ English Abstract)	09/25/2001	KONICA CORP.			
		WO 00/03230	01/20/2000	IA TROQUEST CORP			
		JP 2003-53195 A (w/ English Abstract)	02/25/2003	ARITOMI MASANORI			
		JP 2683452 (w/ English Abstract)	08/08/1997	SUMITOMO ELECTRIC INDUSTRIES LTD.			
		JP 2002-75171 A (w/ English Abstract)	03/15/2002	JAPAN FINE CERAMICS CENTER & SUMITOMO ELECTRIC IND. LTD.			

## OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

EXAMINER'S INITIALS	CITE NO.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.
		N. MIURA et al., "Electroluminescence of ZnF <sub>2</sub> Thin-Films Doped with Rare-Earth Ions", Japanese Journal of Applied Physics, Vol. 31, Part 1, No. 1, January 1992, pages 51-59.
		N. MIURA et al., "Strong Ultraviolet-Emitting ZnF <sub>2</sub> :Gd Thin Film Electroluminescent Device", Japanese Journal of Applied Physics, Vol. 30, No. 10B, October 1991, pages L1815-L1816.

EXAMINER

DATE CONSIDERED

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.